



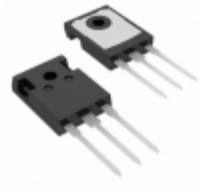
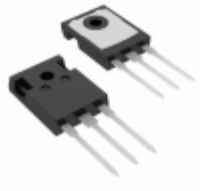


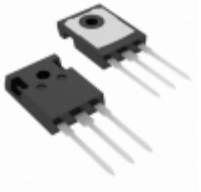
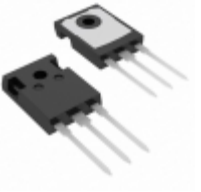
	<h2 style="color: red;">FGH30N60LSDTU</h2>
	<p>Hersteller-Teilenummer: FGH30N60LSDTU</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: IGBT 600V 60A 480W TO247</p> <p>Datenblätter:  FGH30N60LSDTU.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 34163 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FGH30N60LSDTU
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	IGBT 600V 60A 480W TO247
Kategorie	Diskrete Halbleiterprodukte > Transistoren-IGBTs
Teilstatus	34163 pcs Stock
Hersteller Standard Vorlaufzeit	44 Weeks
detaillierte Beschreibung	IGBT 600V 60A 480W Through Hole TO-247
Serie	-
Eingabetyp	Standard
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Leistung - max	480W
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247
Rückwärts-Erholzeit (Trr)	35ns
Strom - Kollektor (Ic) (max)	60A
Spannung - Kollektor-Emitter-Durchbruch (max)	600V
IGBT-Typ	-
VCE (on) (Max) @ Vge, Ic	1.4V @ 15V, 30A
Strom - Collector Pulsed (Icm)	90A
Schaltenergie	1.1mJ (on), 21mJ (off)
Gate-Ladung	225nC
Td (ein / aus) bei 25 ° C	18ns/250ns
Testbedingung	400V, 30A, 6.8 Ohm, 15V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)





FGH30N60LSDTU ist neu im Original, Suche FGH30N60LSDTU Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FGH30N60LSDTU AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FGH30N60LSDTU: Info@Y-IC.com

Sie können auch interessiert sein:

 FGH30N120FTD FSC FGH30N120FTD FSC	 FGH30N60S2 FSC FGH30N60S2 FSC	 FGH30N120FTDTU AMI Semiconductor / ON Semiconductor IGBT 1200V 60A 339W TO247	 FGH30N6S2D AMI Semiconductor / ON Semiconductor IGBT 600V 45A 167W TO247
 FGH30N6S2D Fairchild/ON Semiconductor IGBT 600V 45A 167W TO247	 FGH30N60LSDTU Fairchild/ON Semiconductor IGBT 600V 60A 480W TO247	 FGH30N6S2 AMI Semiconductor / ON Semiconductor IGBT 600V 45A 167W TO247	 FGH30N120FTDTU Fairchild/ON Semiconductor IGBT 1200V 60A 339W TO247

heiße Teile

Mehr

 FGH20N60SFD	 FGH20N60SFDTU	 FGH20N60SFDTU	 FGH20N60UFD	 FGH20N60UFDTU
 FGH20N60UFDTU	 FGH20N6S2	 FGH20N6S2	 FGH20N6S2D	 FGH20N6S2D
 FGH25N120FTDS	 FGH25N120FTDS	 FGH30N120FTD	 FGH30N120FTDTU	 FGH30N120FTDTU
 FGH30N60LSD	 FGH30N60LSDTU	 FGH30N6S2	 FGH30N6S2	 FGH30N6S2D
 FGH30N6S2D	 FGH30S130P	 FGH30S130P	 FGH30T65UPDT	 FGH40N60SF
 FGH40N60SFD	 FGH40N60SFDTU	 FGH40N60SFDTU	 FGH40N60SFTU	 FGH40N60SFTU
 FGH40N60SMD	 FGH40N60SMD	 FGH40N60SMDF	 FGH40N60SMDF	 FGH40N60UF
 FGH40N60UFD	 FGH40N60UFDTU	 FGH40N60UFDTU	 FGH40N60UFTU	 FGH40N60UFTU
 FGH40N65UFD	 FGH40N65UFDTU	 FGH40N65UFDTU	 FGH40N6S2	 FGH40N6S2
 FGH40N6S2D	 FGH40N6S2D	 FGH40T100SMD	 FGH40T100SMD	 FGH40T120SMD

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